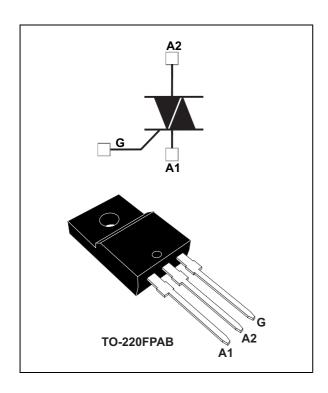
## T435T-600FP



### 4 A Snubberless™ Triac

Datasheet - production data



### **Description**

Available in through-hole package, the Triac T435T-600FP is suitable for general purpose AC switching.

Specially designed for power tool applications, it can also be used to drive loads like motor speed controller, and kitchen equipment such as electro valves, light dimmers and similar.

#### **Features**

- High static and dynamic commutation
- Package is RoHS (2002/95/EC) compliant
- I<sub>GT</sub> = 35 mA
- ECOPACK®2 compliant component
- Provides UL certified insulation rate at 2.0 kV rms

TM: Snubberless is a trademark of STMicroelectronics

Characteristics T435T-600FP

## 1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter				Unit	
I <sub>T(RMS)</sub>	On-state rms current (full sine wave) $T_c = 105  ^{\circ}\text{C}$		4	Α		
l-a	Non repetitive surge peak on-state current (full cycle sine wave, T <sub>J</sub> initial = 25 °C)	F = 60 Hz	t = 16.7 ms	32	Α	
I <sub>TSM</sub>		F = 50 Hz	t = 20 ms	30	Α	
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	value for fusing $t_p = 10 \text{ ms}$		6	A <sup>2</sup> s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$ $F = 120 \text{ Hz}$ $T$		T <sub>j</sub> = 125 °C	50	A/μs	
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage $t_p = 10 \text{ ms}$ $T_j$		T <sub>j</sub> = 25 °C	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V	
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$ $T_j = 125 °C$		4	Α		
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 125  ^{\circ}\text{C}$			1	W	
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			-40 to +150 -40 to +125	°C	

Table 2. Electrical characteristics, Snubberless (3 quadrants)  $(T_i = 25 \, ^{\circ}\text{C}, \text{ unless otherwise specified})$ 

Symbol	Test conditions	Quadrant		Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V R}_L = 30 \Omega$	1 - 11 - 111	MAX	35	mA
V <sub>GT</sub>	$V_D = 12 \text{ V R}_L = 30 \Omega$	1 - 11 - 111	MAX	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM} R_L = 3.3 \text{ k}\Omega$ I - II - III		MIN	0.2	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 100 mA		MAX	35	mA
IL	$I_{G} = 1.2 \times I_{GT}$		MAX	50	mA.
			MAX	80	"
dV/dt (2)	V <sub>D</sub> = 67% V <sub>DRM</sub> , gate open, T <sub>j</sub> = 125 °C			750	V/µs
(dl/dt)c (2)	Without snubber, $T_j = 125 ^{\circ}\text{C}$			5.3	A/ms
V <sub>ins</sub>	Insulation rms voltage, 1 minute			2.0	kV

<sup>1.</sup> Minimum  $\rm I_{GT}$  is guaranteed at 5% of  $\rm I_{GT}$  max.

<sup>2.</sup> For both polarities of A2 pin referenced to A1 pin

T435T-600FP **Characteristics** 

Symbol	Test conditions			Value	Unit
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM} = 5.7 \text{ A}, t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C	MAX	1.6	V
V <sub>TO</sub> <sup>(1)</sup>	Threshold voltage	T <sub>j</sub> = 125 °C	MAX	0.9	V
R <sub>D</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 125 °C	MAX	100	mΩ
I <sub>DRM</sub> V – V	V - V	T <sub>j</sub> = 25 °C	MAX	5	μA
$I_{RRM}$	$V_{DRM} = V_{RRM}$	T <sub>i</sub> = 125 °C	IVIAA	1	mA

Table 3. Static electrical characteristics

**Table 4. Thermal resistances** 

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (ac)	4.3	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	60	S/ VV

1.0 0.5

0.0

25

Figure 1. Maximum power dissipation versus rms on-state current (full cycle)

temperature (full cycle) P(W) 5.0 4.5 4.0 3.5 3.0 2.5 2.0 1.5

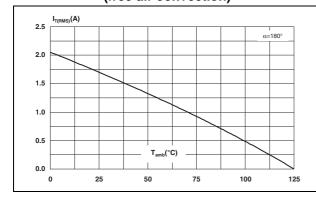
Figure 3. On-state current (rms) versus ambient temperature (free air convection)

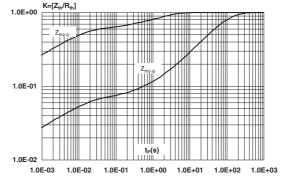
Figure 4. Relative variation of thermal impedance versus pulse duration  $K=[Z_{th}/R_{th}]$ 

T<sub>C</sub>(°C)

50

Figure 2. On-state current (rms) versus case



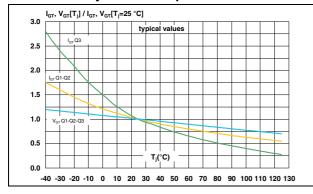


<sup>1.</sup> For both polarities of A2 pin referenced to A1 pin

Characteristics T435T-600FP

Figure 5. Relative variation of gate trigger current, and gate trigger voltage versus junction temperature

Figure 6. Relative variation of holding current and latching current versus junction temperature



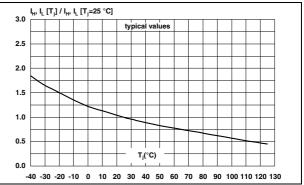
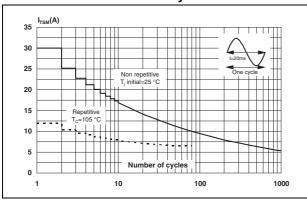


Figure 7. Surge peak on-state current versus number of cycles

Figure 8. Non-repetitive surge peak on-state current for a sinusoidal



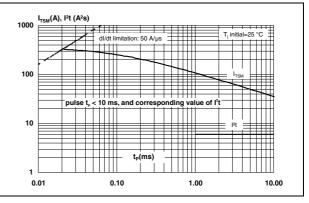
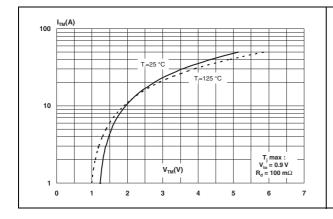
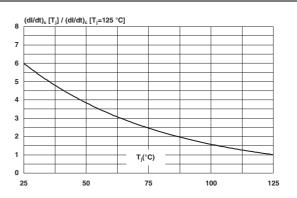


Figure 9. On-state characteristics (maximum values)

Figure 10. Relative variation of critical rate of decrease of main current (dl/dt)c versus junction temperature



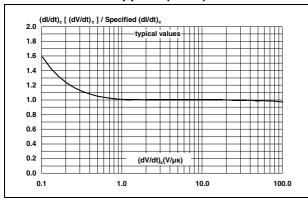


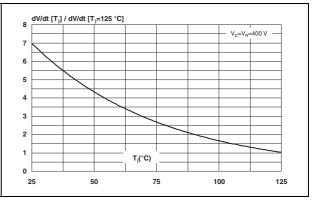
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T435T-600FP Characteristics

Figure 11. Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c

Figure 12. Relative variation of static dV/dt immunity versus junction temperature





Package information T435T-600FP

## 2 Package information

- Epoxy meets UL94, V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

L6 L2 L7 L3 L5 D L4 F2

Figure 13. TO-220FPAB dimension definitions

T435T-600FP Package information

Table 5. TO-220FPAB dimension values

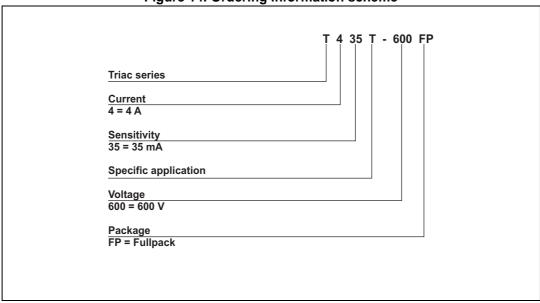
	Dimensions					
Ref.	Millimeters			Inches		
	Min.		Max.	Min.		Max.
А	4.4		4.6	0.173		0.181
В	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
Е	0.45		0.70	0.018		0.027
F	0.75		1	0.030		0.039
F1	1.15		1.70	0.045		0.067
F2	1.15		1.70	0.045		0.067
G	4.95		5.20	0.195		0.205
G1	2.4		2.7	0.094		0.106
Н	10		10.4	0.393		0.409
L2		16 Typ.			0.63 Typ.	
L3	28.6		30.6	1.126		1.205
L4	9.8		10.6	0.386		0.417
L5	2.9		3.6	0.114		0.142
L6	15.9		16.4	0.626		0.646
L7	9.00		9.30	0.354		0.366
Dia.	3.00		3.20	0.118		0.126



Ordering information T435T-600FP

# 3 Ordering information

Figure 14. Ordering information scheme



**Table 6. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Packing mode
T435T-600FP	T435T-600	TO-220FPAB	2.0 g	50	Tube

# 4 Revision history

Table 7. Document revision history

Date	Revision	Changes		
09-Nov-2007	1	Initial release.		
14-Jun-2010	2	Updated ECOPACK statement.		
28-Jul-2014	3	Updated <i>Features</i> , <i>Table 2</i> and <i>Figure 14</i> and reformatted to current standard.		



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